

Voltage Controlled Crystal Oscillator (压控振荡器) - KV708T

Feature 特征

- Frequency pulling range from $\pm 50 \sim \pm 200$ ppm 压控范围 $\pm 50 \sim \pm 200$ ppm
- High frequency ultra-low jitter VCXO, including CMOS, LVPECL, LVDS, CML or HCSL output logics 高频低相位抖动



RoHS
Compliant
KOAN

Applications 应用

- Frequency electrical calibration, high-frequency network application system, military anti-interference communication 频率电校准, 高频网络应用系统, 军事防干扰通讯

General Specifications 规格参考

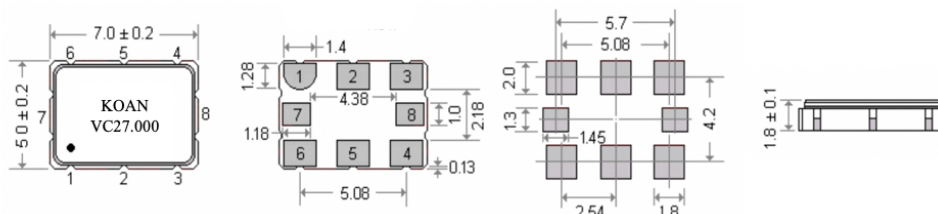
PARAMETER	性能参数	KV708T		
Frequency Range	频率范围	10.0~245.0MHz		
Supply Voltage	供给电压	+1.8V ($\pm 10\%$)	+2.5V ($\pm 10\%$)	+3.3V ($\pm 10\%$)
Center Control Voltage	中心控制电压	0.9Vdc(0V~1.8V)	1.25Vdc(0.25V~2.25V)	1.65Vdc(0.3V~3.0V)
Output Logic	输出波形	CMOS		
Output Load	输出负载	15pF		
Frequency Tolerance	调整频差	± 20 ppm		
Current Consumption	工作电流	70mA typical @50MHz; 80mA typical @250MHz		
Output Logic High "1"	输出电平 高	0.9Vdd min		
Output Logic Low "0"	输出电平 低	0.1Vdd max		
Frequency Pulling Range	压控范围	$\pm 50 \sim \pm 200$ ppm		
Integrated Phase Jitter	抖动	159fs RMS Phase Jitter typ.@156.250MHz (12KHz~20MHz)		
Input Impedance	输入电阻	5M Ω typical		
Rise & Fall Time	上升下降时间	1.0 ns typ.; 5ns max		
Start-up Time	起振时间	5ms typ.; 10ms max		
Linearity	非线性误差	$\pm 1\%$ typ.; $\pm 10\%$ max		
Duty Cycle	占空比	45~55%		
Modulation Bandwidth (-3dB)	调制宽带	10KHz min.		
Aging Per Year	年老化率	± 3 ppm~ ± 5 ppm/year		
Storage Temperature Range	储存温度范围	-55°C ~ +125°C		

Frequency Stability 温度频差 VS Operating Temperature Range 温度范围

Temp. Code	Temp.\ppm	± 10	± 20	± 30	± 50	± 100
B	-20~70°C	○	○	○	○	○
C	-40~85°C		○	○	○	○
D	-20~105°C			○	○	○
E	-40~105°C				○	○
F	-55~105°C					○
G	-20~125°C					○

NOTE: Please consult for other specifications 若有其它规格需求请告知

Outline Dimensions (Unit: mm) 外形尺寸



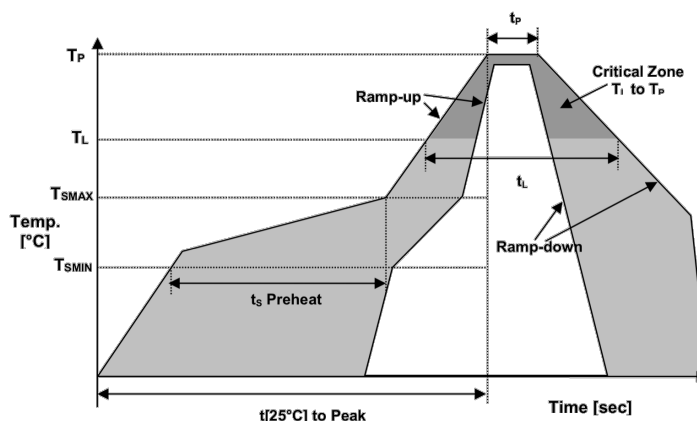
Pin	Connection
#1	Control Voltage
#2	Output Enable
#3	Ground
#4	Output
#5	Complementary Output
#6	Supply Voltage
#7	Do not Connect
#8	Do not Connect

Part Number Guide 产品编号

KV708T - **27.000** - **100** - **33** - **C** - **30** - **NS**

型号	标称频率	压控范围	工作电压	工作温度	温度频差	特殊要求
'KV':产品系列 '708':封装尺寸 SMD 7.0x5.0mm 8pad 'T' 输出波形 CMOS	(In MHz)	50 = ± 50 ppm 100 = ± 100 ppm 150 = ± 150 ppm 200 = ± 200 ppm	18=1.8V 25=2.5V 33=3.3V	B: -20~+70°C C: -40~+85°C D: -20~+105°C E: -40~+105°C F: -55~+105°C G: -20~+125°C	10 = ± 10 ppm 20 = ± 20 ppm 30 = ± 30 ppm 50 = ± 50 ppm 100 = ± 100 ppm	'NS': 特殊要求

Reflow Profile 回流焊



Temperature Min Preheat	最低预热温度	T_{smin}	150°C
Temperature Max preheat	最高预热温度	T_{smax}	200°C
Time (T_{smin} to T_{smax})	时间差	T_s	60~120 sec
Temperature	温度	T_L	217°C
Peak Temperature	最高温	T_p	260 °C
Ramp-up Rate	升温速度	R_{up}	3°C/sec max
Ramp-down Rate	降温速度	R_{down}	6°C/sec max
Time within 5°C of Peak Temperature	最高温度停留时间	t_p	30 sec
Time t[25°C] to peak temperature	25度到最高温度时间	t[25°C] to peak	480 sec
Time	时间	t_L	60~150 sec